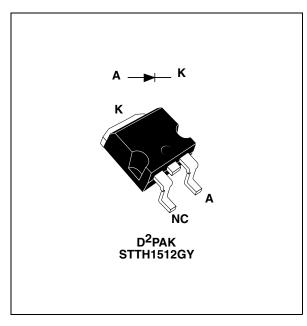




### Automotive ultrafast recovery, high voltage diode

Datasheet - production data



**Table 1. Device summary** 

Symbol	Value
I <sub>F(AV)</sub>	15 A
V <sub>RRM</sub>	1200 V
Tj	175 °C
V <sub>F</sub> (typ)	1.20 V
t <sub>rr</sub> (typ)	53 ns

#### **Features**

- Ultrafast, soft recovery
- Very low conduction and switching losses
- High frequency and/or high pulsed current operation
- High reverse voltage capability
- High junction temperature
- AEC-Q101 qualified

#### **Description**

The high quality design of this diode has produced a device with low leakage current, regularly reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability.

The improved performance in low leakage current, and therefore thermal runaway guard band, is an immediate competitive advantage for this device for automotive applications.

Characteristics STTH1512-Y

#### 1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Paramete	Value	Unit		
$V_{RRM}$	Repetitive peak reverse voltage	1200	V		
I <sub>F(RMS)</sub>	Forward rms current	D <sup>2</sup> PAK		50	А
I <sub>F(AV)</sub>	Average forward current, $\delta = 0.5$	$D^2PAK$ $T_c = 130 °C$		15	А
I <sub>FRM</sub>	Repetitive peak forward current	200	Α		
I <sub>FSM</sub>	Surge non repetitive forward current	200	А		
T <sub>stg</sub>	Storage temperature range	-65 to + 175	°C		
T <sub>j</sub>	Operating junction temperature range	-40 to + 175	°C		

**Table 3. Thermal parameters** 

Symbol	Parameter		Value	Unit
R <sub>th(j-c)</sub>	Junction to case	D <sup>2</sup> PAK	1.3	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage	T <sub>j</sub> = 25 °C	V - V			15	
'R`	current	T <sub>j</sub> = 125 °C	$V_R = V_{RRM}$		10	100	μΑ
		T <sub>j</sub> = 25 °C				2.10	
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 125 °C	I <sub>F</sub> = 15 A		1.25	1.90	V
		T <sub>j</sub> = 150 °C			1.20	1.80	

<sup>1.</sup> Pulse test:  $t_p = 5 \text{ ms}, \delta < 2\%$ 

To evaluate the conduction losses use the following equation:

$$P = 1.4 \times I_{F(AV)} + 0.027 I_{F^{2}(RMS)}$$



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<sup>2.</sup> Pulse test:  $t_p = 380 \mu s$ ,  $\delta < 2\%$ 

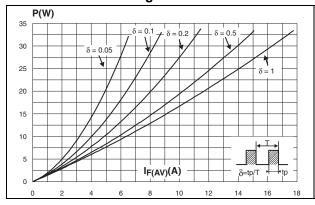
STTH1512-Y Characteristics

**Table 5. Dynamic characteristics** 

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>rr</sub> Reverse recovery time -		$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$			105	2
		$I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		53	75	ns
I <sub>RM</sub>	Reverse recovery current	$I_F = 15 \text{ A}, dI_F/dt = -200 \text{ A/µs},$ $V_R = 600 \text{ V}, T_j = 125 ^{\circ}\text{C}$		20	28	А
S	Softness factor	$I_F = 15 \text{ A}, dI_F/dt = -200 \text{ A/µs},$ $V_R = 600 \text{ V}, T_j = 125 ^{\circ}\text{C}$		1.5		
t <sub>fr</sub>	Forward recovery time	$I_F = 15 \text{ A}$ $dI_F/dt = 50 \text{ A/}\mu\text{s}$ $V_{FR} = 1.5 \text{ x V}_{Fmax}, T_j = 25 \text{ °C}$			600	ns
V <sub>FP</sub>	Forward recovery voltage	$I_F = 15 \text{ A}, dI_F/dt = 50 \text{ A}/\mu\text{s},$ $T_j = 25 \text{ °C}$		5.5		V

Figure 1. Conduction losses versus average current

Figure 2. Forward voltage drop versus forward current



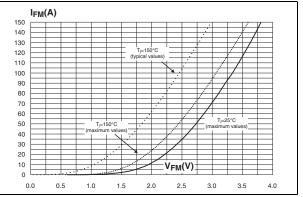
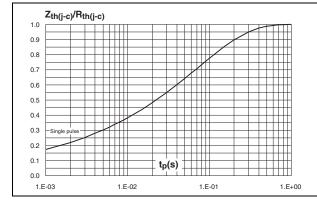
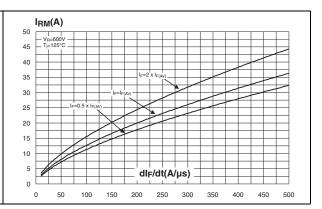


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Figure 4. Peak reverse recovery current versus dl<sub>F</sub>/dt (typical values)

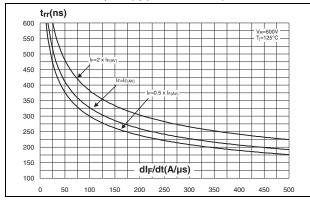




Characteristics STTH1512-Y

Figure 5. Reverse recovery time versus dl<sub>F</sub>/dt (typical values)

Figure 6. Reverse recovery charge versus dl<sub>F</sub>/dt (typical values)



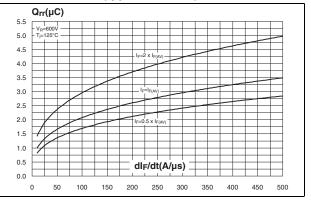
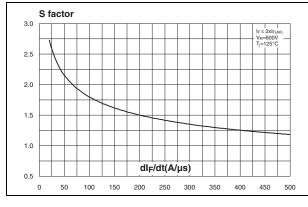
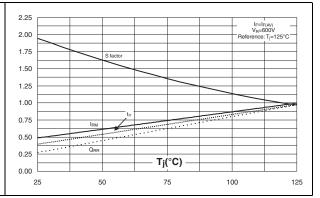


Figure 7. Softness factor versus dl<sub>F</sub>/dt (typical values)

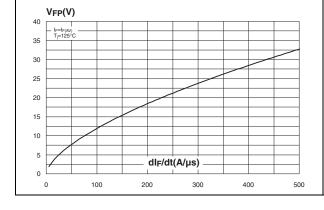
Figure 8. Relative variations of dynamic parameters versus junction temperature

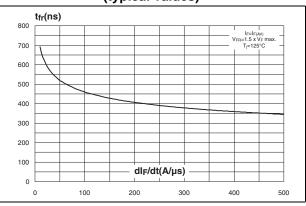




dl<sub>F</sub>/dt (typical values)

Figure 9. Transient peak forward voltage versus Figure 10. Forward recovery time versus dl<sub>F</sub>/dt (typical values)



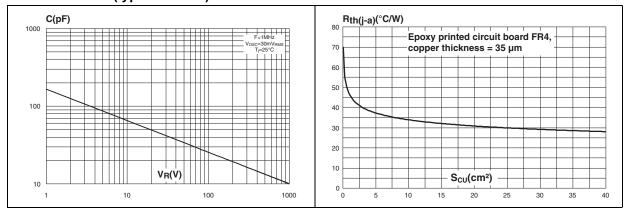


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STTH1512-Y Characteristics

Figure 11. Junction capacitance versus reverse voltage applied (typical values)

Figure 12. Thermal resistance junction to ambient versus copper surface under each lead



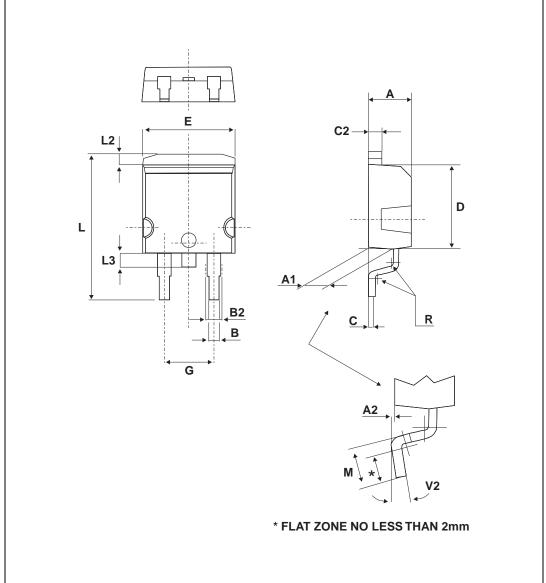
Package information STTH1512-Y

## 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Figure 13. D<sup>2</sup>PAK dimension definitions



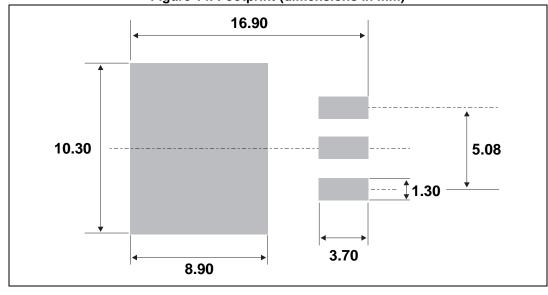
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Table 6. D<sup>2</sup>PAK dimension values

	Dimensions					
Ref.		Millimeters				
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.40		4.60	0.173		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
В	0.70		0.93	0.027		0.037
B2	1.14		1.70	0.045		0.067
С	0.45		0.60	0.017		0.024
C2	1.23		1.36	0.048		0.054
D	8.95		9.35	0.352		0.368
E	10.00		10.40	0.393		0.409
G	4.88	16	5.28	0.192	0.63	0.208
L	15.00		15.85	0.590		0.624
L2	1.27		1.40	0.050		0.055
L3	1.40		1.75	0.055		0.069
М	2.40		3.20	0.094		0.126
R		0.40 typ.			0.016 typ.	
V2	0°		8°	0°		8°

Figure 14. Footprint (dimensions in mm)





Ordering information STTH1512-Y

# **3** Ordering information

**Table 7. Ordering information** 

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH1512GY-TR	STTH1512GY	D²PAK	1.48 g	10000	Tape and reel

## 4 Revision history

**Table 8. Document revision history** 

Date	Revision	Changes
11-Jul-2013	1	Initial release.

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